## NSN 5961-01-121-7731

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View Online at https://aerobasegroup.com/nsn/5961-01-121-7731 **Inclosure Material:** Metal **Overall Length:** 0.325 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 collector to base voltage/static/emitter open and 200.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Test Data Document:** 03640-6096996 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 3 uninsulated wire lead Shelf Life:

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N/a

**Unit Of Measure:** 

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No

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